Small Signal Fast Switching Diode

FEATURES

- Silicon epitaxial planar diode
- Low forward voltage drop
- High forward current capability
- QuadroMELF package
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT

DESIGN SUPPORT TOOLS click logo to get started

3D Models Available

APPLICATIONS

- High speed switch and general purpose
- Use in computer and industrial applications

MECHANICAL DATA

Case: QuadroMELF (SOD-80)

Weight: approx. 34 mg

Cathode band color: black

Packaging codes / options:

GS18/10K per 13" reel (8 mm tape), 10K/box

GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

PARTS TABLE

PART	ORDERING CODE	TYPE MARKING	CIRCUIT CONFIGURATION	REMARKS
LS4150	LS4150GS18 or LS4150GS08	-	Single	Tape and reel

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Repetitive peak reverse voltage		V_{RRM}	50	V
Reverse voltage		V_R	50	V
Peak forward surge current	t_p = 1 µs	I_{FSM}	4	A
Forward continuous current		I_F	600	mA
Average forward current	V_R = 0	$I_{F(AV)}$	300	mA
Power dissipation		P_{tot}	500	mW

THERMAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R_{thJA}	300	K/W
Junction temperature		T_j	175	°C
Storage temperature range		T_{stg}	-65 to +175	°C

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 1 mA	V_F	0.540		0.620	V
	I_F = 10 mA	V_F	0.660		0.740	V
	I_F = 50 mA	V_F	0.760		0.860	V
	I_F = 100 mA	V_F	0.820		0.920	V
	I_F = 200 mA	V_F	0.870		1	V
Reverse current	V_R = 50 V	I_R			100	nA
	V_R = 50 V, T_j = 150 °C	I_R			100	µA
Diode capacitance	V_R = 0, f = 1 MHz, V_{HF} = 50 mV	C_D			2.5	pF
Reverse recovery time	I_F = I_R = 10 mA to 100 mA, i_R = 0.1 x I_R, R_L = 100 Ω	t_{rr}			4	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

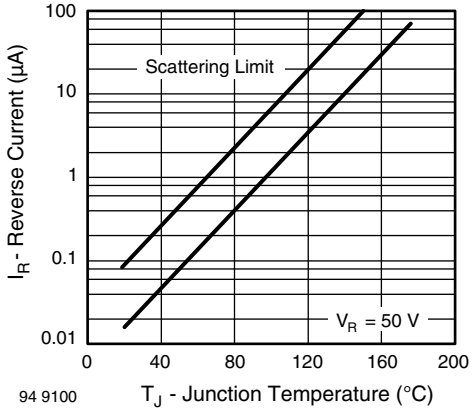


Fig. 1 - Reverse Current vs. Junction Temperature

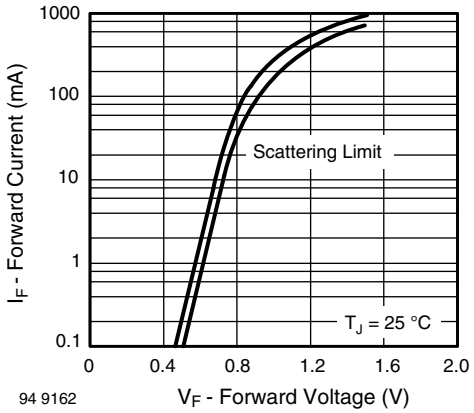
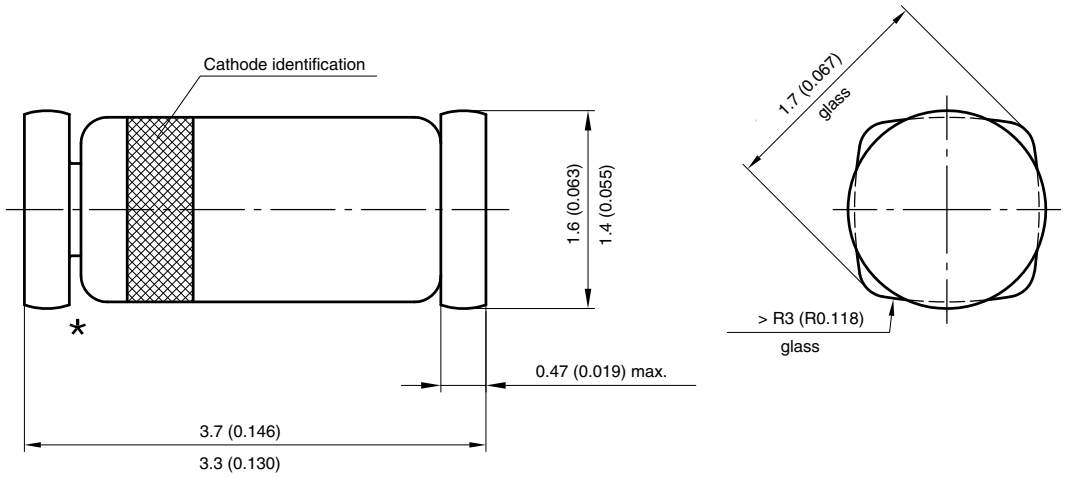


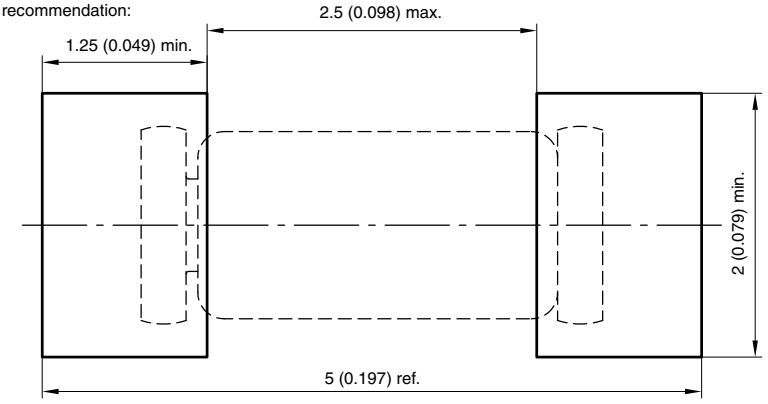
Fig. 2 - Forward Current vs. Forward Voltage

PACKAGE DIMENSIONS in millimeters (inches): **QuadroMELF (SOD-80)**



* The gap between plug and glass can be either on cathode or anode side

Foot print recommendation:



Created - Date: 03.November.2003
Rev. 11 - Date: 07.June 2006
Document no.:6.560-5006.01-4
96 12071

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